

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	42829	(organic WITH layer) WITH (conductive OR anode OR cathode OR electrode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWE NT; IBM_TD B	2006/08/06 14:52
2	BRS	L2	190959	transparent WITH (anode OR cathode OR conductive OR electrode OR metal\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWE NT; IBM_TD B	2006/08/06 14:53
3	BRS	L3	16068	1 AND 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWE NT; IBM_TD B	2006/08/06 14:42
4	BRS	L4	28183	(transistor OR TFT) WITH ((passivation OR insulat\$3) ADJ layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWE NT; IBM_TD B	2006/08/06 14:53

	Type	L #	Hits	Search Text	DBs	Time Stamp
5	BRS	L5	1793	3 AND 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWE NT; IBM_T DB	2006/08/06 14:43
6	BRS	L6	14270	transparent WITH (anode OR cathode OR conductive OR electrode OR metal\$3) WITH organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWE NT; IBM_T DB	2006/08/06 14:54
7	BRS	L7	862	5 AND 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWE NT; IBM_T DB	2006/08/06 14:44
8	BRS	L8	3752	((organic WITH layer) WITH (conductive OR anode OR cathode OR electrode)).CLM.	US-PGPUB	2006/08/06 14:53
9	BRS	L9	7643	(transparent WITH (anode OR cathode OR conductive OR electrode OR metal\$3)).CLM.	US-PGPUB	2006/08/06 14:53
10	BRS	L10	929	8 AND 9	US-PGPUB	2006/08/06 14:53
11	BRS	L11	2483	((transistor OR TFT) WITH ((passivation OR insulat\$3) ADJ layer)).CLM.	US-PGPUB	2006/08/06 14:54

	Type	L #	Hits	Search Text	DBs	Time Stamp
12	BRS	L12	83	10 AND 11	US-PGPUB	2006/08/06 14:54
13	BRS	L13	831	(transparent WITH (anode OR cathode OR conductive OR electrode OR metal\$3) WITH organic).CLM.	US-PGPUB	2006/08/06 14:55
14	BRS	L14	43	12 AND 13	US-PGPUB	2006/08/06 14:55